All Oxide Based Flexible Multi-Folded Invisible Synapse as Vision Photo-receptor

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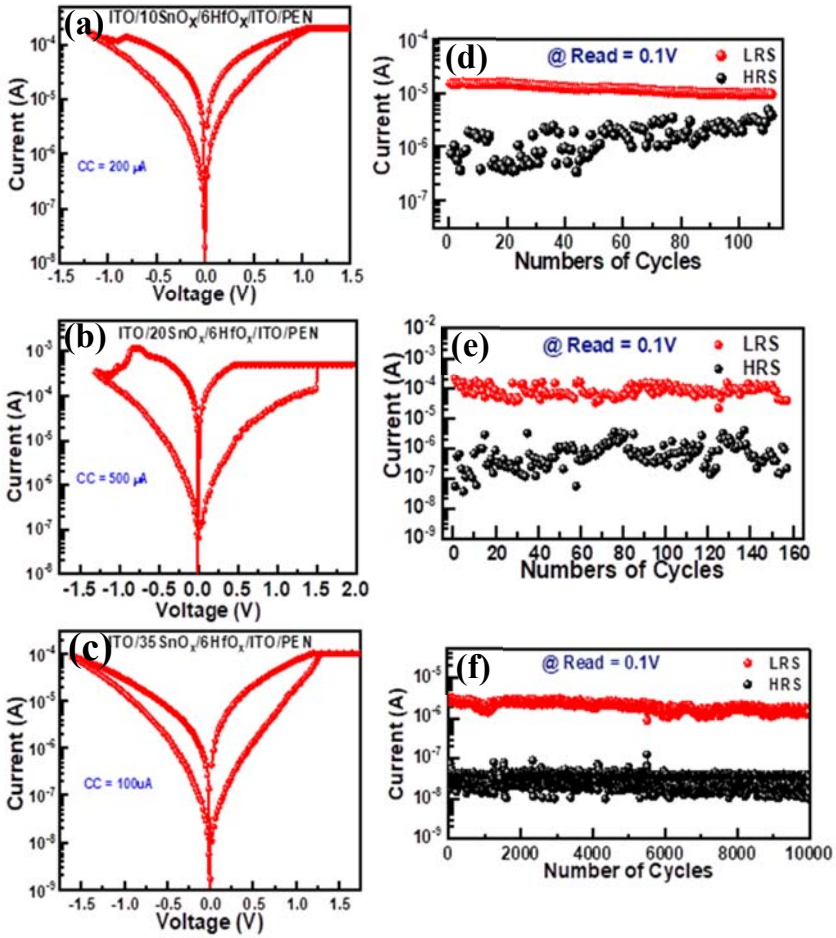

Figure S1: (a), (b) and (c): The optimization of the current-voltage bipolar switching curves of different SnO_x thicknesses of 5, 20 and 35 nm devices having 6 nm HfO_x layer for each device ; (e), (f) and (g) are the corresponding endurance results, respectively. The minimum compliance current is used to obtain the best switching and endurance performances. The 35 nm thick SnO_x layer device can sustain well for more than 10000 cycles along with gradual switching at a low compliance current.